## AM3455P

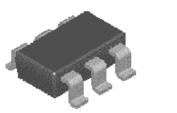
## **Analog Power**

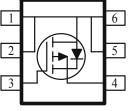
## P-Channel 30V (D-S) MOSFET

These miniature surface mount MOSFETs utilize High Cell Density process. Low  $r_{DS(on)}$  assures minimal power loss and conserves energy, making this device ideal for use in power management circuitry. Typical applications are power switch, power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

- Low r<sub>DS(on)</sub> Provides Higher Efficiency and Extends Battery Life
- Low Gate Charge
- Fast Switch
- Miniature TSOP-6 Surface Mount Package Saves Board Space

| PRODUCT SUMMARY     |                                |     |  |
|---------------------|--------------------------------|-----|--|
| V <sub>DS</sub> (V) | $r_{DS(on)}(\Omega)$ $I_D(A)$  |     |  |
| -30                 | 0.112 @ V <sub>GS</sub> = 10 V | 3.4 |  |
|                     | $0.172 @ V_{GS} = 4.5V$        | 2.7 |  |





| ABSOLUTE MAXIMUM RATINGS (T <sub>A</sub> = 25 °C UNLESS OTHERWISE NOTED) |  |                 |            |       |  |  |
|--|--|-----------------|------------|-------|--|--|
| Parameter  |  |                 | Maximum    | Units |  |  |
| Drain-Source Voltage   |  |                 | -30 V      |       |  |  |
| Gate-Source Voltage  |  |                 | ±20        | v     |  |  |
| Continuous Drain Current <sup>a</sup>                                    | $T_A=25^{\circ}C$                          | T <sub>n</sub>  | 3.4        | А     |  |  |
| Continuous Drain Current   | $T_{A}=25^{\circ}C$ $T_{A}=70^{\circ}C$    | тр              | 2.6        |       |  |  |
| Pulsed Drain Current <sup>b</sup>  |  | I <sub>DM</sub> | ±20        | ±20   |  |  |
| Continuous Source Current (Diode Conduction) <sup>a</sup>                |  |                 | 1.7        | А     |  |  |
|  | $T_A=25^{\circ}C$                          | D               | 2.0        | W     |  |  |
| Power Dissipation <sup>a</sup>   | $T_{A}=25^{\circ}C$<br>$T_{A}=70^{\circ}C$ | ГD              | 1.3        | ٧V    |  |  |
| Operating Junction and Storage Temperature Range                         |  |                 | -55 to 150 | °C    |  |  |

| THERMAL RESISTANCE RATINGS               |              |                   |         |       |  |
|--|--------------|-------------------|---------|-------|--|
| Parameter                                |              | Symbol            | Maximum | Units |  |
| Maximum Junction-to-Ambient <sup>a</sup> | t <= 5 sec   | D                 | 62.5    | °C/W  |  |
|  | Steady-State | R <sub>THJA</sub> | 110     |       |  |

Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

| SPECIFICATIONS ( $T_A = 25^{\circ}C$ UNLESS OTHERWISE NOTED) |                     |  |        |     |      |      |  |
|--|---------------------|--|--------|-----|------|------|--|
| <b>Parameter</b>   | Symbol              | Test Conditions  | Limits |     |      | Unit |  |
| i ar anne te i   | Symbol              | Test conditions  | Min    | Тур | Max  | Omt  |  |
| Static   |                     |  |        |     |      | -    |  |
| Gate-Threshold Voltage                                       | V <sub>GS(th)</sub> | $V_{DS} = V_{GS}, I_D = 250 \text{ uA}$  | 1.0    |     |      | v    |  |
| Gate-Body Leakage  | Igss                | $V_{DS} = 0 V, V_{GS} = \pm 20 V$  |        |     | ±100 | nA   |  |
| Zero Gate Voltage Drain Current                              | IDSS                | $V_{DS} = -24 V$ , $V_{GS} = 0 V$  |        |     | 1    |      |  |
| Zelo Gate voltage Dialii Current                             | IDSS                | $V_{DS} = -24 V, V_{GS} = 0 V, T_J = 55^{\circ}C$  |        |     | 50   | uA   |  |
| On-State Drain Current <sup>A</sup>                          | ID(on)              | $V_{DS} = 5 V, V_{GS} = 10 V$  | 10     |     |      | Α    |  |
| Drain-Source On-Resistance <sup>A</sup>                      | rDS(on)             | $V_{GS} = 10 V$ , $I_D = 3.4 A$  |        |     | 112  | mΩ   |  |
|  |                     | $V_{GS} = 4.5 \text{ V}, I_D = 2.7 \text{ A}$  |        |     | 172  |      |  |
| Forward Tranconductance <sup>A</sup>                         | g <sub>fs</sub>     | $V_{DS} = 4.5 V$ , $I_D = 3.4 A$   |        | 6   |      | S    |  |
| Diode Forward Voltage  | Vsd                 | $I_S = 0.75 A$ , $V_{GS} = 0 V$  |        |     | 1.2  | V    |  |
| Dynamic <sup>b</sup>   |                     |  |        |     |      |      |  |
| Total Gate Charge  | Qg                  | $V_{DS} = 30 \text{ V}, V_{GS} = 5 \text{ V}, I_D = 3.4 \text{ A}$                       |        | 4.5 |      | nC   |  |
| Gate-Source Charge   | Qgs                 |  |        | 1.4 |      |      |  |
| Gate-Drain Charge  | Qgd                 |  |        | 2.4 |      |      |  |
| Turn-On Delay Time   | td(on)              |  |        | 9   |      |      |  |
| Rise Time  | tr                  | $V_{DD} = 30 \text{ V},  R_L = 30 \Omega,  I_D = 1 \text{ A}, \\ V_{GEN} = 10 \text{ V}$ |        | 12  |      | ns   |  |
| Turn-Off Delay Time  | td(off)             |  |        | 25  |      |      |  |
| Fall-Time  | tf                  |  |        | 14  |      |      |  |

Notes

a. Pulse test:  $PW \le 300$ us duty cycle  $\le 2\%$ .

b. Guaranteed by design, not subject to production testing.

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